Infineon Technologies - MB96F696RBPMC-GSE2 Datasheet

Welcome to E-XFL.COM

What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Obsolete
Core Processor	F²MC-16FX
Core Size	16-Bit
Speed	32MHz
Connectivity	CANbus, I²C, LINbus, SCI, UART/USART
Peripherals	DMA, LCD, LVD, POR, PWM, WDT
Number of I/O	77
Program Memory Size	288KB (288K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 27x8/10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-LQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/mb96f696rbpmc-gse2

- Internal clock divider and prescaler provide exact 1s clock

External Interrupts

- Edge or Level sensitive
- Interrupt mask bit per channel
- Each available CAN channel RX has an external interrupt for wake-up
- Selected USART channels SIN have an external interrupt for wake-up

Non Maskable Interrupt

- Disabled after reset, can be enabled by Boot-ROM depending on ROM configuration block
- Once enabled, cannot be disabled other than by reset
- High or Low level sensitive
- Pin shared with external interrupt 0

I/O Ports

- Most of the external pins can be used as general purpose I/O
- All push-pull outputs(except when used as I^2C SDA/SCL line)
- Bit-wise programmable as input/output or peripheral signal
- Bit-wise programmable input enable
- One input level per GPIO-pin (either Automotive or CMOS hysteresis)
- Bit-wise programmable pull-up resistor

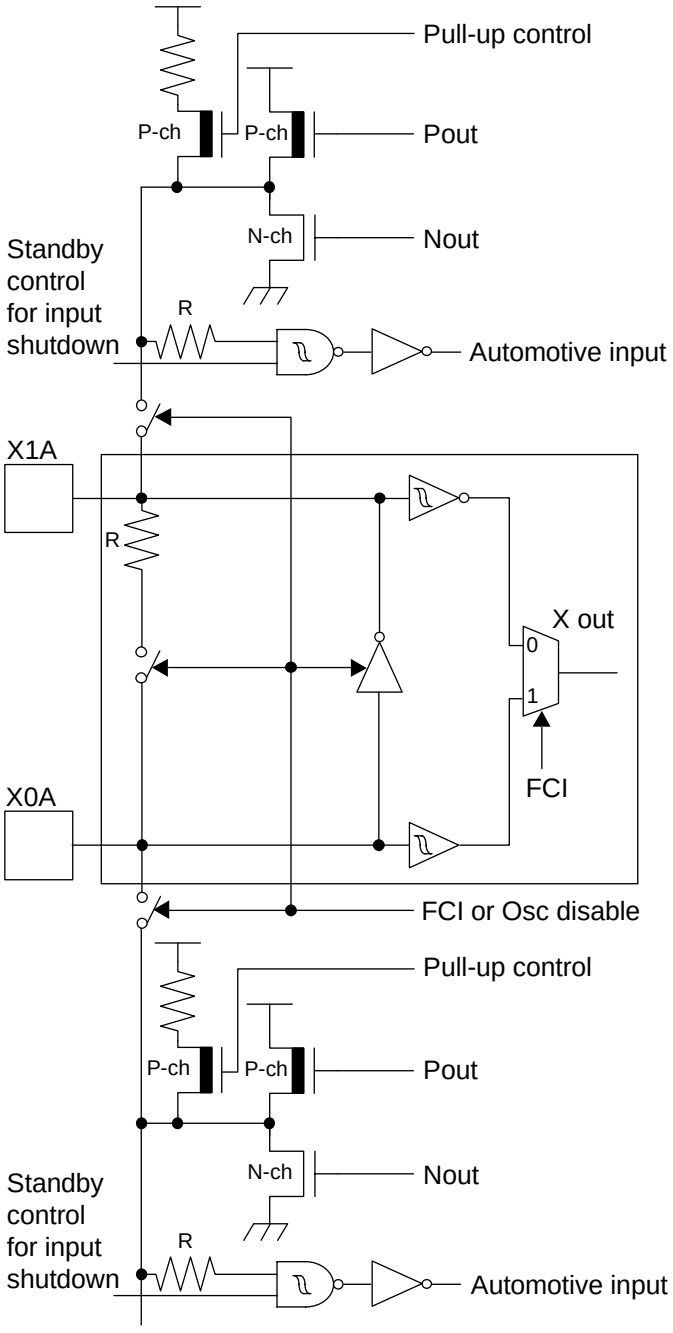
Built-in On Chip Debugger (OCD)

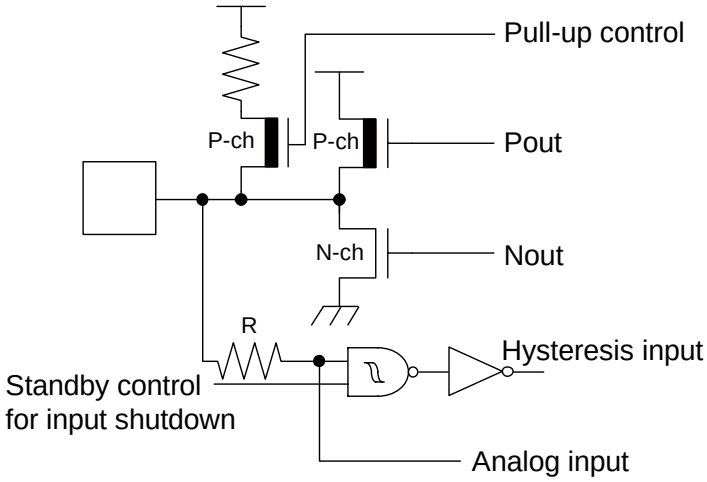
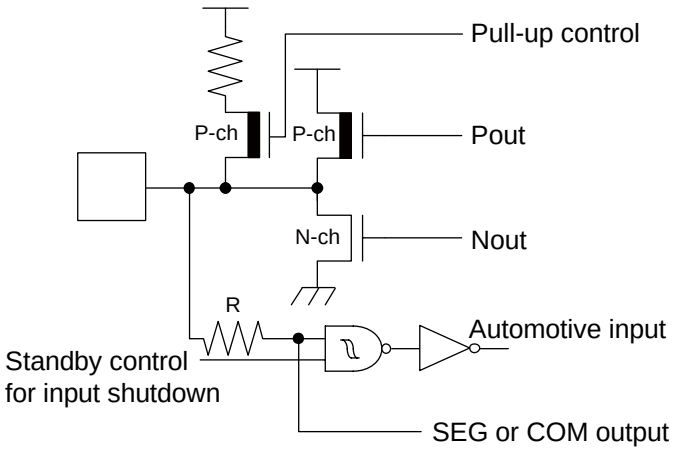
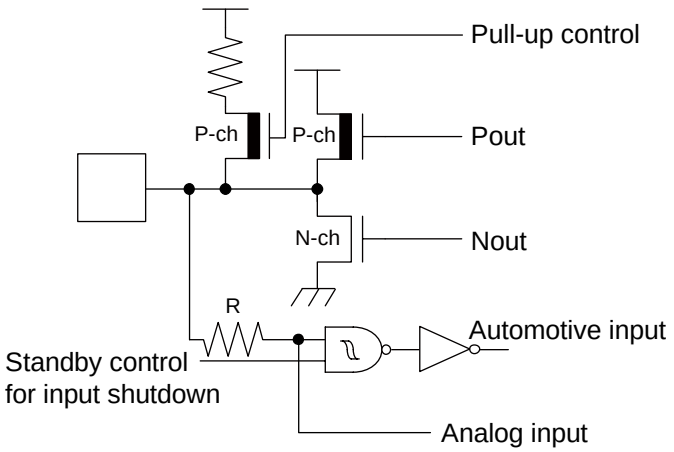
- One-wire debug tool interface
- Break function:
  - Hardware break: 6 points (shared with code event)
  - Software break: 4096 points
- Event function
  - Code event: 6 points (shared with hardware break)
  - Data event: 6 points
  - Event sequencer: 2 levels + reset
- Execution time measurement function
- Trace function: 42 branches
- Security function

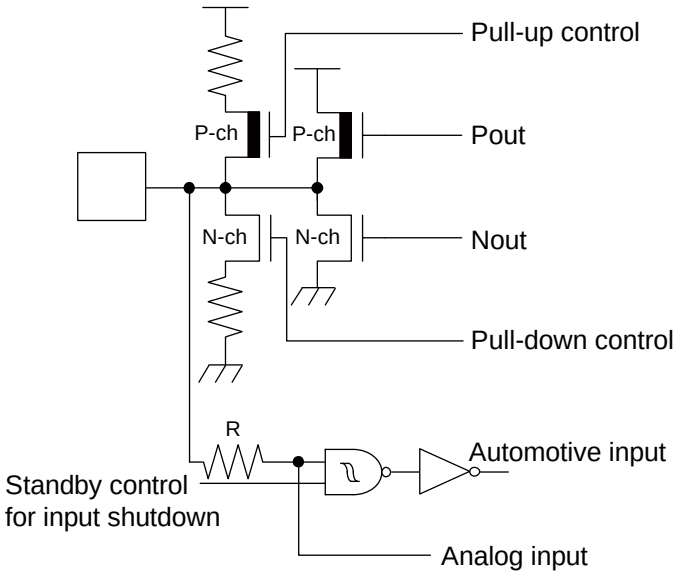
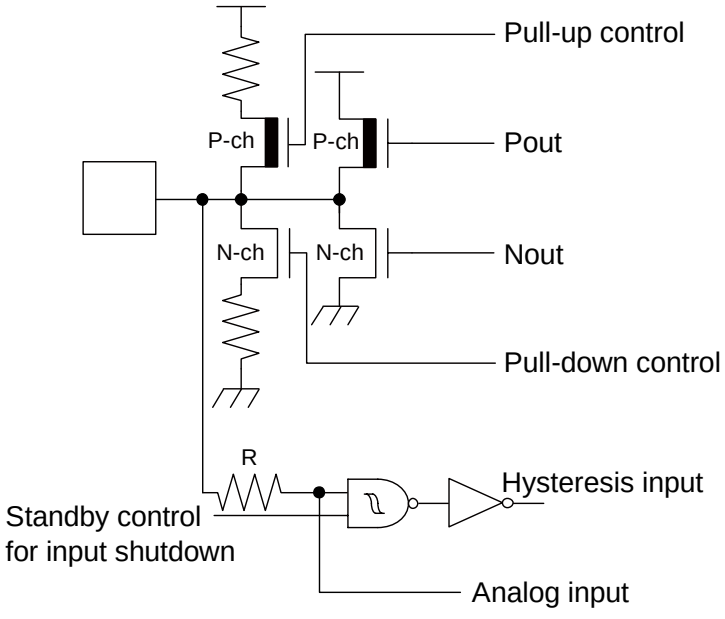
Flash Memory

- Dual operation flash allowing reading of one Flash bank while programming or erasing the other bank
- Command sequencer for automatic execution of programming algorithm and for supporting DMA for programming of the Flash Memory
- Supports automatic programming, Embedded Algorithm
- Write/Erase/Erase-Suspend/Resume commands
- A flag indicating completion of the automatic algorithm
- Erase can be performed on each sector individually
- Sector protection
- Flash Security feature to protect the content of the Flash
- Low voltage detection during Flash erase or write

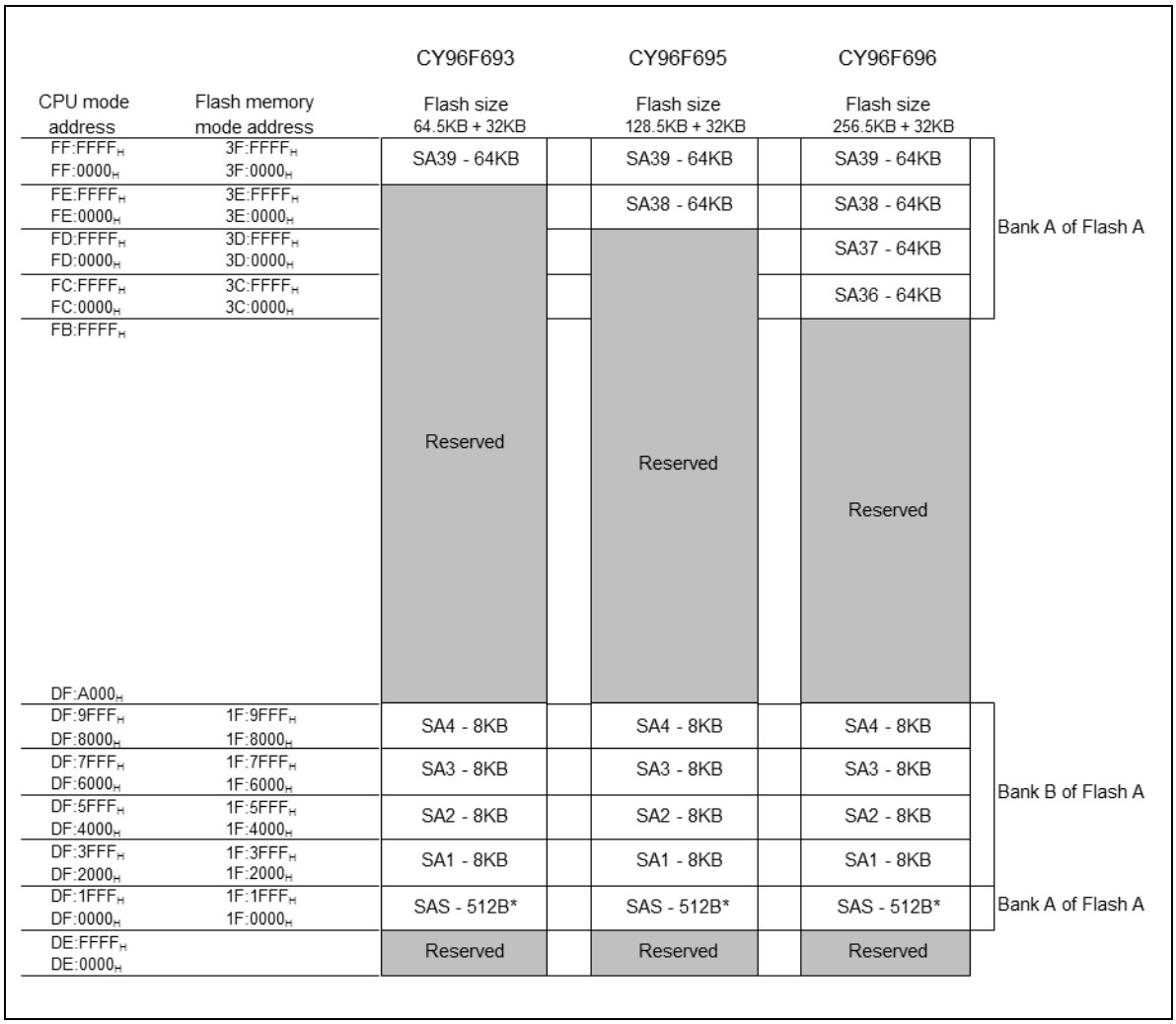
Pin No.	I/O Circuit Type*	Pin Name
39	R	P08_7 / PWM2M1 / AN23 / PPG7_B
40	R	P09_0 / PWM1P2 / AN24
41	R	P09_1 / PWM1M2 / AN25
42	R	P09_2 / PWM2P2 / AN26
43	R	P09_3 / PWM2M2 / AN27
44	Supply	DV_{cc}
45	Supply	DV_{ss}
46	S	P10_0 / PWM1P4 / SIN2 / TIN3 / INT11 / AN28
47	R	P10_1 / PWM1M4 / SOT2 / TOT3 / AN29
48	S	P10_2 / PWM2P4 / SCK2 / PPG6 / AN30
49	R	P10_3 / PWM2M4 / PPG7 / AN31
50	Supply	Vcc
51	Supply	V_{ss}
52	O	DEBUG I/F
53	H	P17_0
54	C	MD
55	A	X0
56	A	X1
57	Supply	V_{ss}
58	B	P04_0 / X0A
59	B	P04_1 / X1A
60	C	RSTX
61	J	P11_0 / COM0
62	J	P11_1 / COM1 / PPG0_R
63	J	P11_2 / COM2 / PPG1_R
64	J	P11_3 / COM3 / PPG2_R
65	J	P11_4 / SEG0 / PPG3_R
66	J	P11_5 / SEG1 / PPG4_R
67	J	P11_6 / SEG2 / FRCK0_R
68	J	P11_7 / SEG3 / IN0_R
69	J	P12_0 / SEG4 / IN1_R
70	J	P12_3 / SEG7 / OUT2_R
71	J	P12_7 / SEG11 / INT1_R
72	J	P00_0 / SEG12 / INT3_R
73	J	P00_1 / SEG13 / INT4_R
74	J	P00_2 / SEG14 / INT5_R
75	Supply	V_{cc}
76	Supply	V_{ss}
77	J	P00_3 / SEG15 / INT6_R

Type	Circuit	Remarks
B		Low-speed oscillation circuit shared with GPIO functionality: ■ Feedback resistor = approx. 5.0MΩ ■ GPIO functionality selectable (CMOS level output (I_{OL} = 4mA, I_{OH} = -4mA), Automotive input with input shutdown function and programmable pull-up resistor)

Type	Circuit	Remarks
I		■ CMOS level output (I_{OL} = 4mA, I_{OH} = -4mA) ■ CMOS hysteresis input with input shutdown function ■ Programmable pull-up resistor ■ Analog input
J		■ CMOS level output (I_{OL} = 4mA, I_{OH} = -4mA) ■ Automotive input with input shutdown function ■ Programmable pull-up resistor ■ SEG or COM output
K		■ CMOS level output (I_{OL} = 4mA, I_{OH} = -4mA) ■ Automotive input with input shutdown function ■ Programmable pull-up resistor ■ Analog input

Type	Circuit	Remarks
R		■ CMOS level output (programmable I_{OL} = 4mA, I_{OH} = -4mA and I_{OL} = 30mA, I_{OH} = -30mA) ■ Automotive input with input shutdown function ■ Programmable pull-up / pull-down resistor ■ Analog input
S		■ CMOS level output (programmable I_{OL} = 4mA, I_{OH} = -4mA and I_{OL} = 30mA, I_{OH} = -30mA) ■ CMOS hysteresis input with input shutdown function ■ Programmable pull-up / pull-down resistor ■ Analog input

9. User ROM Memory Map for Flash Devices



CPU mode address	Flash memory mode address	CY96F693 Flash size 64.5KB + 32KB	CY96F695 Flash size 128.5KB + 32KB	CY96F696 Flash size 256.5KB + 32KB	
FF:FFFF$_H$ FF:0000$_H$	3F:FFFF$_H$ 3F:0000$_H$	SA39 - 64KB	SA39 - 64KB	SA39 - 64KB	Bank A of Flash A
FE:FFFF$_H$ FE:0000$_H$	3E:FFFF$_H$ 3E:0000$_H$	Reserved	SA38 - 64KB	SA38 - 64KB	
FD:FFFF$_H$ FD:0000$_H$	3D:FFFF$_H$ 3D:0000$_H$		Reserved	SA37 - 64KB	
FC:FFFF$_H$ FC:0000$_H$	3C:FFFF$_H$ 3C:0000$_H$			SA36 - 64KB	
FB:FFFF$_H$				Reserved	
DF:A000$_H$					
DF:9FFF$_H$ DF:8000$_H$	1F:9FFF$_H$ 1F:8000$_H$	SA4 - 8KB	SA4 - 8KB	SA4 - 8KB	Bank B of Flash A
DF:7FFF$_H$ DF:6000$_H$	1F:7FFF$_H$ 1F:6000$_H$	SA3 - 8KB	SA3 - 8KB	SA3 - 8KB	
DF:5FFF$_H$ DF:4000$_H$	1F:5FFF$_H$ 1F:4000$_H$	SA2 - 8KB	SA2 - 8KB	SA2 - 8KB	
DF:3FFF$_H$ DF:2000$_H$	1F:3FFF$_H$ 1F:2000$_H$	SA1 - 8KB	SA1 - 8KB	SA1 - 8KB	
DF:1FFF$_H$ DF:0000$_H$	1F:1FFF$_H$ 1F:0000$_H$	SAS - 512B*	SAS - 512B*	SAS - 512B*	Bank A of Flash A
DE:FFFF$_H$ DE:0000$_H$		Reserved	Reserved	Reserved	

*: Physical address area of SAS-512B is from DF:0000$_H$ to DF:01FF$_H$.
Others (from DF:0200$_H$ to DF:1FFF$_H$) is mirror area of SAS-512B.
Sector SAS contains the ROM configuration block RCBA at CPU address DF:0000$_H$ -DF:01FF$_H$.
SAS cannot be used for E^{2}PROM emulation.

11. Interrupt Vector Table

Vector Number	Offset in Vector Table	Vector Name	Cleared by DMA	Index in ICR to Program	Description
0	$3FC_H$	CALLV0	No	-	CALLV instruction
1	$3F8_H$	CALLV1	No	-	CALLV instruction
2	$3F4_H$	CALLV2	No	-	CALLV instruction
3	$3F0_H$	CALLV3	No	-	CALLV instruction
4	$3EC_H$	CALLV4	No	-	CALLV instruction
5	$3E8_H$	CALLV5	No	-	CALLV instruction
6	$3E4_H$	CALLV6	No	-	CALLV instruction
7	$3E0_H$	CALLV7	No	-	CALLV instruction
8	$3DC_H$	RESET	No	-	Reset vector
9	$3D8_H$	INT9	No	-	INT9 instruction
10	$3D4_H$	EXCEPTION	No	-	Undefined instruction execution
11	$3D0_H$	NMI	No	-	Non-Maskable Interrupt
12	$3CC_H$	DLY	No	12	Delayed Interrupt
13	$3C8_H$	RC_TIMER	No	13	RC Clock Timer
14	$3C4_H$	MC_TIMER	No	14	Main Clock Timer
15	$3C0_H$	SC_TIMER	No	15	Sub Clock Timer
16	$3BC_H$	LVDI	No	16	Low Voltage Detector
17	$3B8_H$	EXTINT0	Yes	17	External Interrupt 0
18	$3B4_H$	EXTINT1	Yes	18	External Interrupt 1
19	$3B0_H$	EXTINT2	Yes	19	External Interrupt 2
20	$3AC_H$	EXTINT3	Yes	20	External Interrupt 3
21	$3A8_H$	EXTINT4	Yes	21	External Interrupt 4
22	$3A4_H$	EXTINT5	Yes	22	External Interrupt 5
23	$3A0_H$	EXTINT6	Yes	23	External Interrupt 6
24	$39C_H$	EXTINT7	Yes	24	External Interrupt 7
25	398_H	EXTINT8	Yes	25	External Interrupt 8
26	394_H	EXTINT9	Yes	26	External Interrupt 9
27	390_H	EXTINT10	Yes	27	External Interrupt 10
28	$38C_H$	EXTINT11	Yes	28	External Interrupt 11
29	388_H	EXTINT12	Yes	29	External Interrupt 12
30	384_H	EXTINT13	Yes	30	External Interrupt 13
31	380_H	EXTINT14	Yes	31	External Interrupt 14
32	$37C_H$	EXTINT15	Yes	32	External Interrupt 15
33	378_H	CAN0	No	33	CAN Controller 0
34	374_H	-	-	34	Reserved
35	370_H	-	-	35	Reserved
36	$36C_H$	-	-	36	Reserved
37	368_H	-	-	37	Reserved
38	364_H	PPG0	Yes	38	Programmable Pulse Generator 0
39	360_H	PPG1	Yes	39	Programmable Pulse Generator 1

13. Handling Devices

Special Care is Required for the following when Handling the Device:

- Latch-up prevention
- Unused pins handling
- External clock usage
- Notes on PLL clock mode operation
- Power supply pins (Vcc/Vss)
- Crystal oscillator and ceramic resonator circuit
- Turn on sequence of power supply to A/D converter and analog inputs
- Pin handling when not using the A/D converter
- Notes on Power-on
- Stabilization of power supply voltage
- SMC power supply pins
- Serial communication
- Mode Pin (MD)

13.1 Latch-Up Prevention

CMOS IC chips may suffer latch-up under the following conditions:

- A voltage higher than V_{CC} or lower than V_{SS} is applied to an input or output pin.
- A voltage higher than the rated voltage is applied between Vcc pins and Vss pins.
- The AV_{CC} power supply is applied before the V_{CC} voltage.

Latch-up may increase the power supply current dramatically, causing thermal damages to the device.

For the same reason, extra care is required to not let the analog power-supply voltage (AV_{CC}, AVRH) exceed the digital power-supply voltage.

13.2 Unused Pins Handling

Unused input pins can be left open when the input is disabled (corresponding bit of Port Input Enable register

PIER = 0).

Leaving unused input pins open when the input is enabled may result in misbehavior and possible permanent

damage of the device. To prevent latch-up, they must therefore be pulled up or pulled down through resistors which should be more than 2kΩ.

Unused bidirectional pins can be set either to the output state and be then left open, or to the input state with

either input disabled or external pull-up/pull-down resistor as described above.

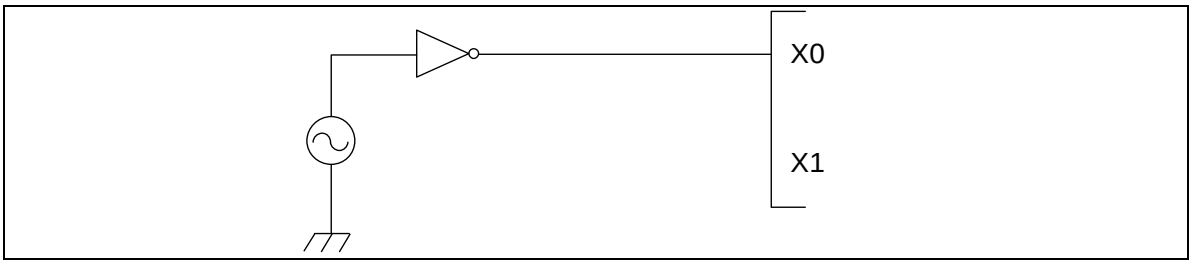
13.3 External Clock Usage

The permitted frequency range of an external clock depends on the oscillator type and configuration.

See AC Characteristics for detailed modes and frequency limits. Single and opposite phase external clocks must be connected as follows:

13.3.1 *Single Phase External Clock for Main Oscillator*

When using a single phase external clock for the Main oscillator, X0 pin must be driven and X1 pin left open.
And supply 1.8V power to the external clock.

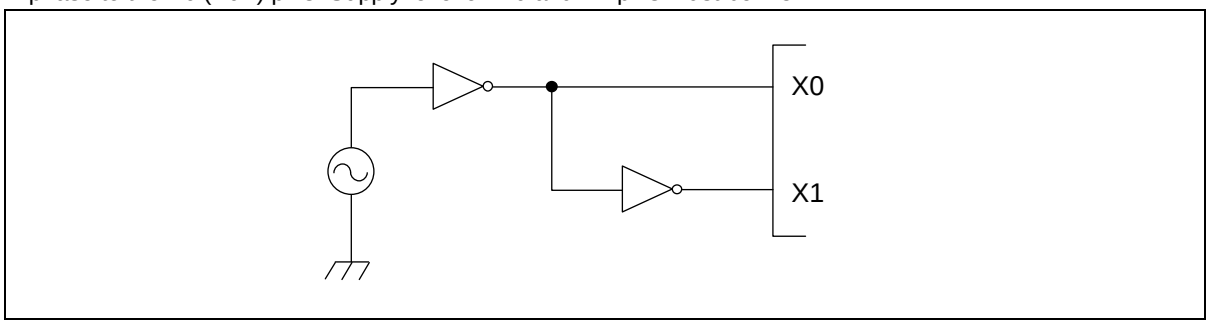


13.3.2 *Single Phase External Clock for Sub Oscillator*

When using a single phase external clock for the Sub oscillator, “External clock mode” must be selected and X0A/P04_0 pin must be driven. X1A/P04_1 pin can be configured as GPIO.

13.3.3 *Opposite Phase External Clock*

When using an opposite phase external clock, X1 (X1A) pins must be supplied with a clock signal which has the opposite phase to the X0 (X0A) pins. Supply level on X0 and X1 pins must be 1.8V.



13.4 Notes on PLL Clock Mode Operation

If the microcontroller is operated with PLL clock mode and no external oscillator is operating or no external clock is supplied, the microcontroller attempts to work with the free oscillating PLL. Performance of this operation, however, cannot be guaranteed.

13.5 Power Supply Pins (Vcc/Vss)

It is required that all V_{CC}-level as well as all V_{SS}-level power supply pins are at the same potential. If there is more than one V_{CC} or V_{SS} level, the device may operate incorrectly or be damaged even within the guaranteed operating range.

Vcc and Vss pins must be connected to the device from the power supply with lowest possible impedance.

The smoothing capacitor at Vcc pin must use the one of a capacity value that is larger than Cs.

Besides this, as a measure against power supply noise, it is required to connect a bypass capacitor of about 0.1μF between Vcc and Vss pins as close as possible to Vcc and Vss pins.

13.6 Crystal Oscillator and ceramic resonator Circuit

Noise at X0, X1 pins or X0A, X1A pins might cause abnormal operation. It is required to provide bypass capacitors with shortest possible distance to X0, X1 pins and X0A, X1A pins, crystal oscillator (or ceramic resonator) and ground lines, and, to the utmost effort, that the lines of oscillation circuit do not cross the lines of other circuits.

It is highly recommended to provide a printed circuit board art work surrounding X0, X1 pins and X0A, X1A pins with a ground area for stabilizing the operation.

It is highly recommended to evaluate the quartz/MCU or resonator/MCU system at the quartz or resonator manufacturer, especially when using low-Q resonators at higher frequencies.

13.7 Turn on Sequence of Power Supply to A/D Converter and Analog Inputs

It is required to turn the A/D converter power supply (AV_{CC}, AVRH, AVRL) and analog inputs (ANn) on after turning the digital power supply (V_{CC}) on.

14. Electrical Characteristics

14.1 Absolute Maximum Ratings

Parameter	Symbol	Condition	Rating		Unit	Remarks
			Min	Max		
Power supply voltage[1]	V_{CC}	-	V_{SS} - 0.3	V_{SS} + 6.0	V	
Analog power supply voltage[1]	AV_{CC}	-	V_{SS} - 0.3	V_{SS} + 6.0	V	$V_{CC} = AV_{CC}$[2]
Analog reference voltage[1]	AVRH, AVRL	-	V_{SS} - 0.3	V_{SS} + 6.0	V	$AV_{CC} \geq$ AVRH, $AV_{CC} \geq$ AVRL, AVRH > AVRL, AVRL ≥ AV_{SS}
SMC Power supply[1]	DV_{CC}	-	V_{SS} - 0.3	V_{SS} + 6.0	V	$V_{CC} = AV_{CC} = DV_{CC}$[2]
LCD power supply voltage[1]	V0 to V3	-	V_{SS} - 0.3	V_{SS} + 6.0	V	V0 to V3 must not exceed V_{CC}
Input voltage[1]	V_I	-	V_{SS} - 0.3	V_{SS} + 6.0	V	$V_I \leq (D)V_{CC} + 0.3V$[3]
Output voltage[1]	V_O	-	V_{SS} - 0.3	V_{SS} + 6.0	V	$V_O \leq (D)V_{CC} + 0.3V$[3]
Maximum Clamp Current	I_{CLAMP}	-	-4.0	+4.0	mA	Applicable to general purpose I/O pins [4]
Total Maximum Clamp Current	$\Sigma\lvert I_{CLAMP}\rvert$	-	-	25	mA	Applicable to general purpose I/O pins [4]
"L" level maximum output current	I_{OL}	-	-	15	mA	Normal port
	I_{OLSMC}	T_A= -40°C	-	52	mA	High current port
		T_A= +25°C	-	39	mA	
		T_A= +85°C	-	32	mA	
		T_A= +105°C	-	30	mA	
"L" level average output current	I_{OLAV}	-	-	4	mA	Normal port
	$I_{OLAVSMC}$	T_A= -40°C	-	40	mA	High current port
		T_A= +25°C	-	30	mA	
		T_A= +85°C	-	25	mA	
		T_A= +105°C	-	23	mA	
"L" level maximum overall output current	ΣI_{OL}	-	-	50	mA	Normal port
	ΣI_{OLSMC}	-	-	260	mA	High current port
"L" level average overall output current	ΣI_{OLAV}	-	-	25	mA	Normal port
	$\Sigma I_{OLAVSMC}$	-	-	170	mA	High current port

Parameters	Symbol	Pin Name	Conditions	Value			Unit	Remarks
				Min	Typ	Max		
"H" level output voltage	V_{OH4}	4mA type	$4.5V \le (D)V_{CC} \le 5.5V$ I_{OH} = -4mA	$(D)V_{CC}$- 0.5	-	$(D)V_{CC}$	V	
			$2.7V \le (D)V_{CC} < 4.5V$ I_{OH} = -1.5mA					
	V_{OH30}	High Drive type*	$4.5V \le DV_{CC} \le 5.5V$ I_{OH} = -52mA	DV_{CC}- 0.5	-	DV_{CC}	V	T_A = -40°C
			$2.7V \le DV_{CC} < 4.5V$ I_{OH} = -18mA					
			$4.5V \le DV_{CC} \le 5.5V$ I_{OH} = -39mA					T_A = +25°C
			$2.7V \le DV_{CC} < 4.5V$ I_{OH} = -16mA					
			$4.5V \le DV_{CC} \le 5.5V$ I_{OH} = -32mA					T_A = +85°C
			$2.7V \le DV_{CC} < 4.5V$ I_{OH} = -14.5mA					
			$4.5V \le DV_{CC} \le 5.5V$ I_{OH} = -30mA					T_A = +105°C
			$2.7V \le DV_{CC} < 4.5V$ I_{OH} = -14mA					
	V_{OH3}	3mA type	$4.5V \le V_{CC} \le 5.5V$ I_{OH} = -3mA	V_{CC}- 0.5	-	V_{CC}	V	
			$2.7V \le V_{CC} < 4.5V$ I_{OH} = -1.5mA					

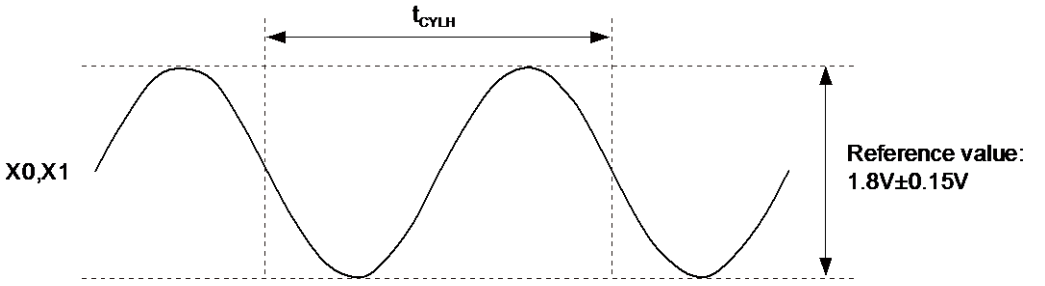
14.4 AC Characteristics

14.4.1 *Main Clock Input Characteristics*

(V_{CC} = AV_{CC} = DV_{CC} = 2.7V to 5.5V, VD=1.8V±0.15V, V_{SS} = AV_{SS} = DV_{SS} = 0V, T_A = - 40°C to + 105°C)

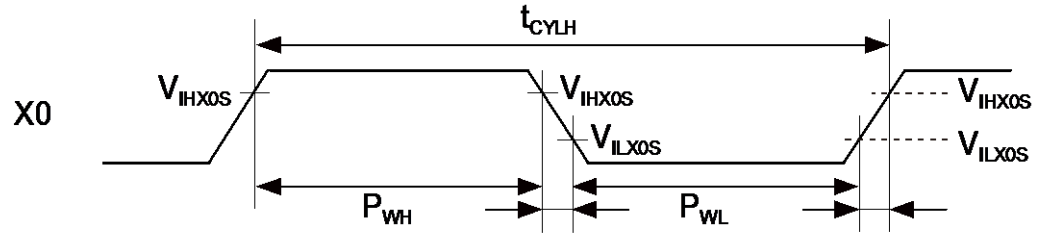
Parameter	Symbol	Pin Name	Value			Unit	Remarks
			Min	Typ	Max		
Input frequency	f_C	X0, X1	4	-	8	MHz	When using a crystal oscillator, PLL off
			-	-	8	MHz	When using an opposite phase external clock, PLL off
			4	-	8	MHz	When using a crystal oscillator or opposite phase external clock, PLL on
Input frequency	f_{FCI}	X0	-	-	8	MHz	When using a single phase external clock in “Fast Clock Input mode”, PLL off
			4	-	8	MHz	When using a single phase external clock in “Fast Clock Input mode”, PLL on
Input clock cycle	t_{CYLH}	-	125	-	-	ns	
Input clock pulse width	P_{WH}, P_{WL}	-	55	-	-	ns	

When using the crystal oscillator



The amplitude changes by resistance, capacity which added outside or the difference of the device.

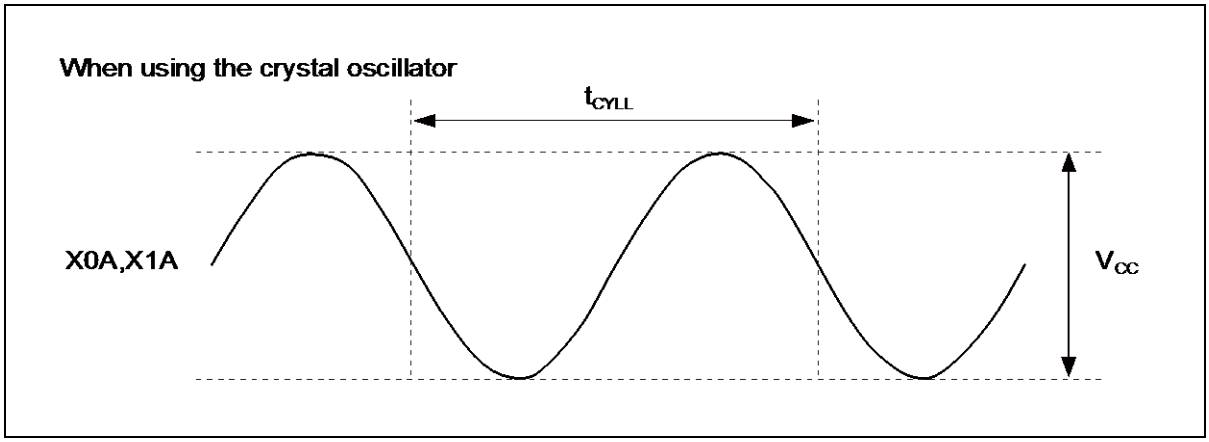
When using the external clock

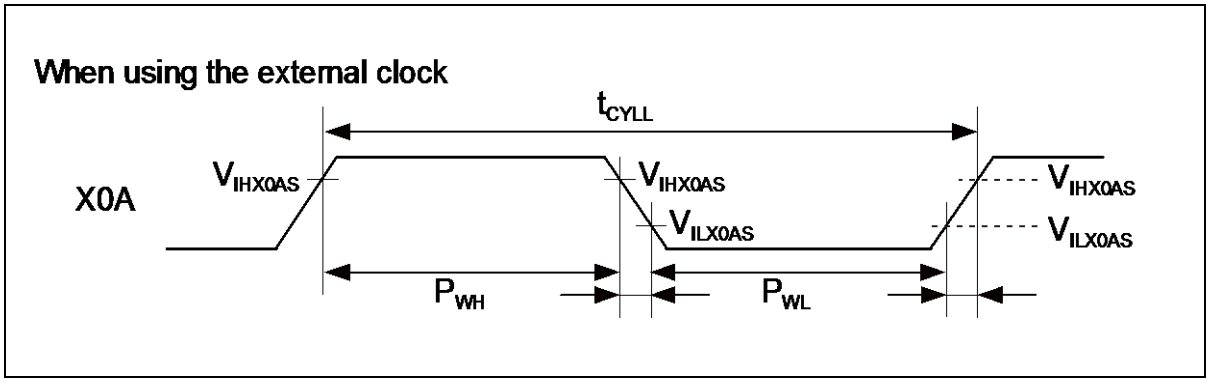


14.4.2 *Sub Clock Input Characteristics*

(V_{CC} = AV_{CC} = DV_{CC} = 2.7V to 5.5V, V_{SS} = AV_{SS} = DV_{SS} = 0V, T_A = - 40°C to + 105°C)

Parameter	Symbol	Pin Name	Conditions	Value			Unit	Remarks
				Min	Typ	Max		
Input frequency	f_{CL}	X0A, X1A	-	-	32.768	-	kHz	When using an oscillation circuit
			-	-	-	100	kHz	When using an opposite phase external clock
		X0A	-	-	-	50	kHz	When using a single phase external clock
Input clock cycle	t_{CYLL}	-	-	10	-	-	µs	
Input clock pulse width	-	-	P_{WH}/t_{CYLL}, P_{WL}/t_{CYLL}	30	-	70	%	

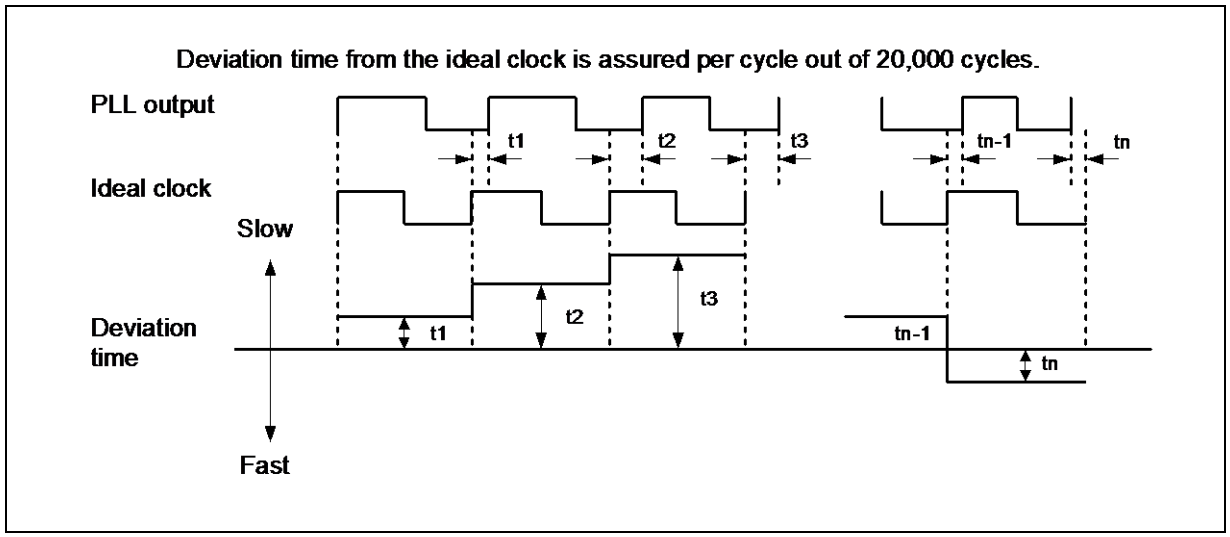




14.4.5 *Operating Conditions of PLL*

(V_{CC} = AV_{CC} = DV_{CC} = 2.7V to 5.5V, V_{SS} = AV_{SS} = DV_{SS} = 0V, T_A = - 40°C to + 105°C)

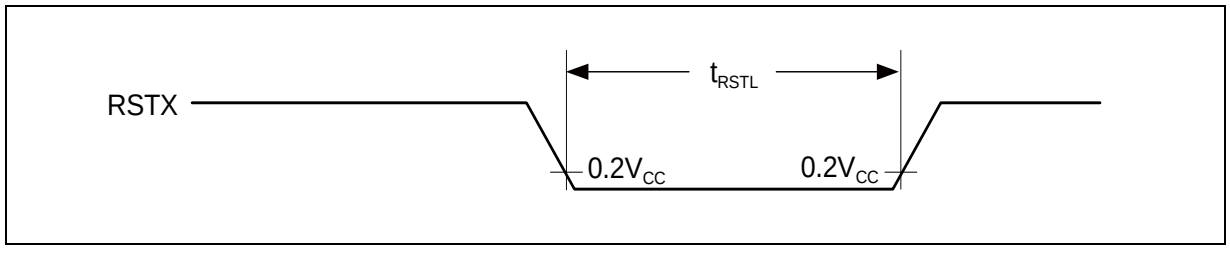
Parameter	Symbol	Value			Unit	Remarks
		Min	Typ	Max		
PLL oscillation stabilization wait time	t_{LOCK}	1	-	4	ms	For CLKMC = 4MHz
PLL input clock frequency	f_{PLLI}	4	-	8	MHz	
PLL oscillation clock frequency	f_{CLKVCO}	56	-	108	MHz	Permitted VCO output frequency of PLL (CLKVCO)
PLL phase jitter	t_{PSKEW}	-5	-	+5	ns	For CLKMC (PLL input clock) ≥ 4MHz

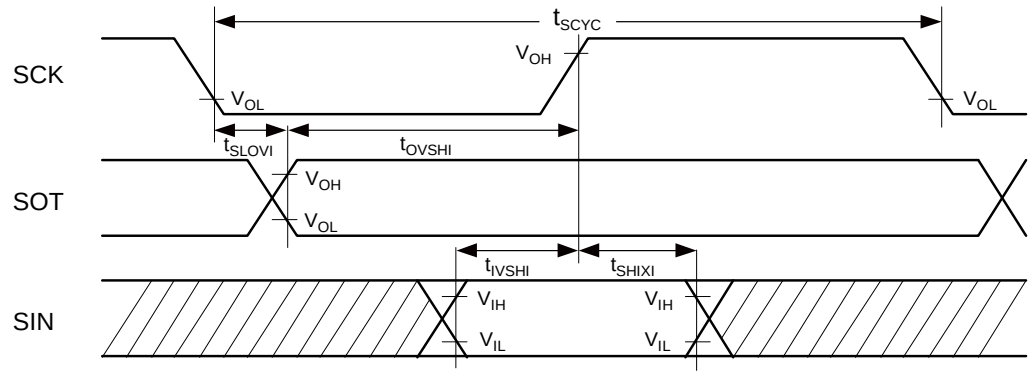


14.4.6 *Reset Input*

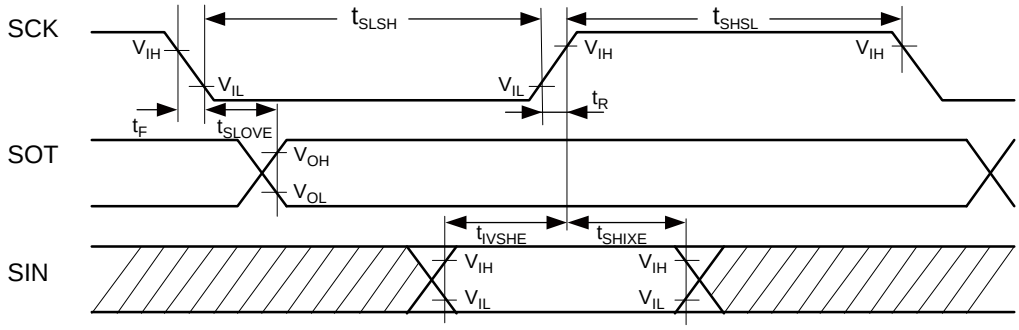
(V_{CC} = AV_{CC} = DV_{CC} = 2.7V to 5.5V, V_{SS} = AV_{SS} = DV_{SS} = 0V, T_A = - 40°C to + 105°C)

Parameter	Symbol	Pin Name	Value		Unit
			Min	Max	
Reset input time	t_{RSTL}	RSTX	10	-	µs
Rejection of reset input time			1	-	µs





Internal shift clock mode



External shift clock mode

14.4.10 *I²C Timing*

(V_{CC} = AV_{CC} = DV_{CC} = 2.7V to 5.5V, V_{SS} = AV_{SS} = DV_{SS} = 0V, T_A = - 40°C to + 105°C)

Parameter	Symbol	Conditions	Typical Mode		High-Speed Mode[4]		Unit
			Min	Max	Min	Max	
SCL clock frequency	f_{SCL}	C_L = 50pF, R = (Vp/I_{OL})[1]	0	100	0	400	kHz
(Repeated) START condition hold time SDA ↓ → SCL ↓	t_{HDSTA}		4.0	-	0.6	-	µs
SCL clock "L" width	t_{LOW}		4.7	-	1.3	-	µs
SCL clock "H" width	t_{HIGH}		4.0	-	0.6	-	µs
(Repeated) START condition setup time SCL ↑ → SDA ↓	t_{SUSTA}		4.7	-	0.6	-	µs
Data hold time SCL ↓ → SDA ↓ ↑	t_{HDDAT}		0	3.45[2]	0	0.9[3]	µs
Data setup time SDA ↓ ↑ →SCL ↑	t_{SUDAT}		250	-	100	-	ns
STOP condition setup time SCL ↑ → SDA ↑	t_{SUSTO}		4.0	-	0.6	-	µs
Bus free time between "STOP condition" and "START condition"	t_{BUS}		4.7	-	1.3	-	µs
Pulse width of spikes which will be suppressed by input noise filter	t_{SP}	-	0	(1-1.5) ×t_{CLKP1}[5]	0	(1-1.5) ×t_{CLKP1}[5]	ns

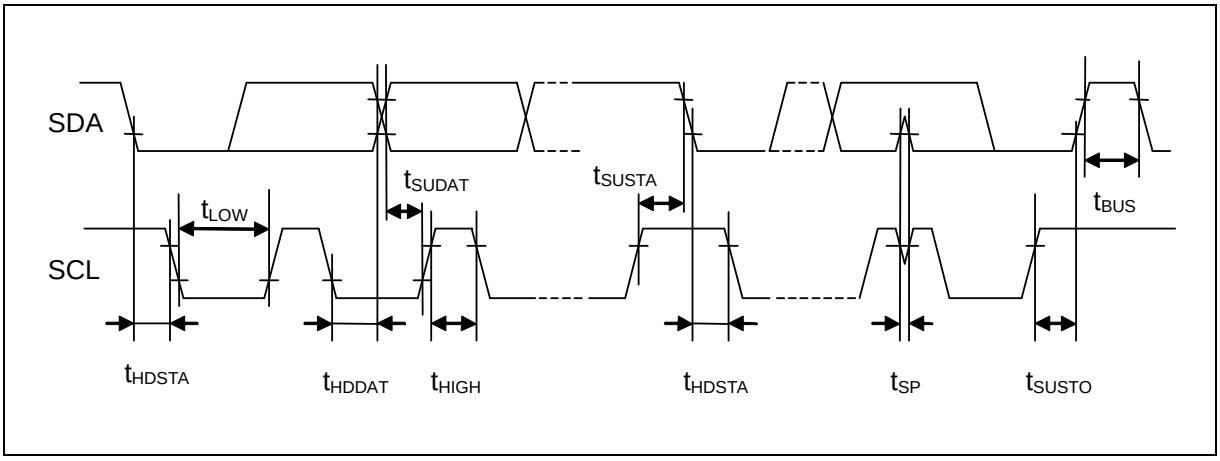
[1]: R and C_L represent the pull-up resistance and load capacitance of the SCL and SDA lines, respectively. Vp indicates the power supply voltage of the pull-up resistance and I_{OL} indicates V_{OL} guaranteed current.

[2]: The maximum t_{HDDAT} only has to be met if the device does not extend the "L" width (t_{LOW}) of the SCL signal.

[3]: A high-speed mode I^2C bus device can be used on a standard mode I^2C bus system as long as the device satisfies the requirement of "t_{SUDAT} ≥ 250ns".

[4]: For use at over 100 kHz, set the peripheral clock1 (CLKP1) to at least 6 MHz.

[5]: t_{CLKP1} indicates the peripheral clock1 (CLKP1) cycle time.



14.8 Flash Memory Write/Erase Characteristics

(V_{CC} = AV_{CC} = DV_{CC} = 2.7V to 5.5V, V_{SS} = AV_{SS} = DV_{SS} = 0V, T_A = - 40°C to + 105°C)

Parameter		Conditions	Value			Unit	Remarks
			Min	Typ	Max		
Sector erase time	Large Sector	-	-	1.6	7.5	s	Includes write time prior to internal erase.
	Small Sector	-	-	0.4	2.1	s	
	Security Sector	-	-	0.31	1.65	s	
Word (16-bit) write time		-	-	25	400	µs	Not including system-level overhead time.
Chip erase time		-	-	8.31	40.05	s	Includes write time prior to internal erase.

Note:

While the Flash memory is written or erased, shutdown of the external power (V_{CC}) is prohibited. In the application system where the external power (V_{CC}) might be shut down while writing or erasing, be sure to turn the power off by using a low voltage detection function.

To put it concrete, change the external power in the range of change ration of power supply voltage (-0.004V/µs to +0.004V/µs) after the external power falls below the detection voltage (V_{DLX})[1].

Write/Erase cycles and data hold time

Write/Erase Cycles (Cycle)	Data Hold Time (Year)
1,000	20 [2]
10,000	10 [2]
100,000	5 [2]

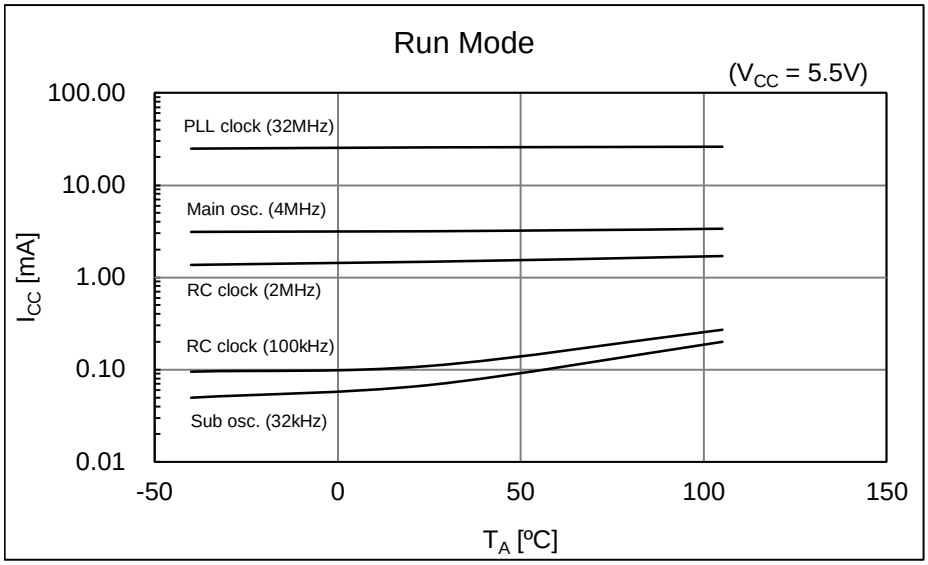
[1]: See "14.7 Low Voltage Detection Function Characteristics".

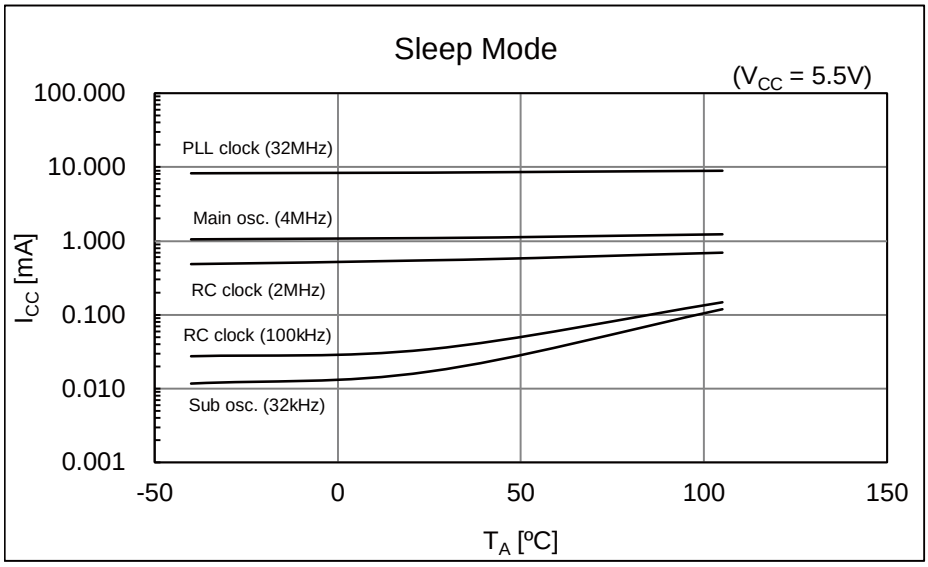
[2]: This value comes from the technology qualification (using Arrhenius equation to translate high temperature measurements into normalized value at + 85°C).

15. Example Characteristics

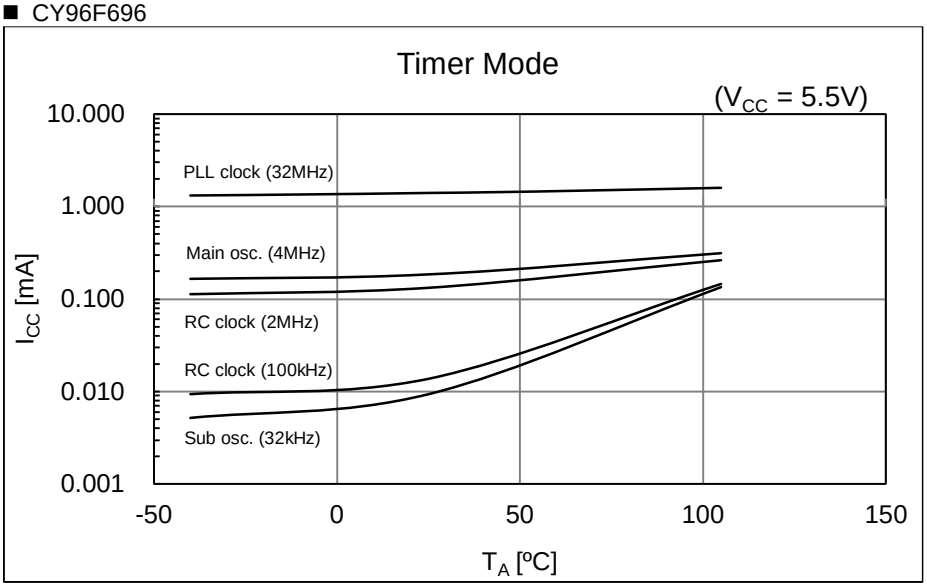
This characteristic is an actual value of the arbitrary sample. It is not the guaranteed value.

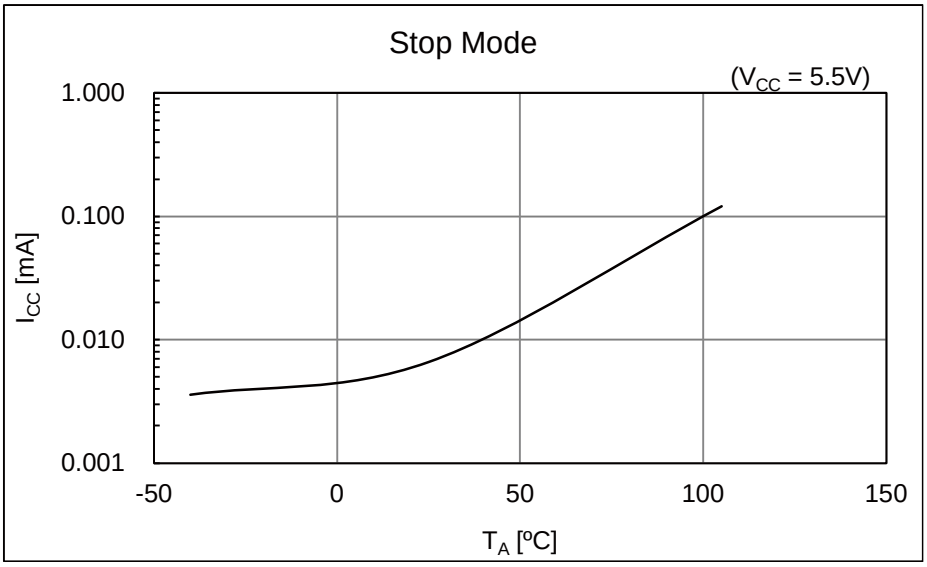
■ CY96F696





■ CY96F696


Timer Mode
(V_{CC} = 5.5V)
10.000
1.000
0.100
0.010
0.001
I_{CC} [mA]
PLL clock (32MHz)
Main osc. (4MHz)
RC clock (2MHz)
RC clock (100kHz)
Sub osc. (32kHz)
-50
0
50
100
150
T_A [ºC]


Stop Mode
(V_{CC} = 5.5V)
1.000
0.100
0.010
0.001
I_{CC} [mA]
-50
0
50
100
150
T_A [ºC]

Page	Section	Change Results
		Added Remarks to “PLL oscillation clock frequency”
		Added “ PLL phase jitter” and the figure
	4. AC Characteristics (6) Reset Input	Added the figure for reset input time (t_{RSTL})
51	4. AC Characteristics (8) USART Timing	Changed the condition (V_{CC} = AV_{CC} = DV_{CC} = 2.7V to 5.5V, V_{SS} = AV_{SS} = DV_{SS} = 0V, T_A = - 40°C to + 105°C) (V_{CC} = AV_{CC} = DV_{CC} = 2.7V to 5.5V, V_{SS} = AV_{SS} = DV_{SS} = 0V, T_A = - 40°C to + 105°C, C_L = 50pF)
		Changed the HARDWARE MANUAL “MB96690 series HARDWARE MANUAL” “MB96600 series HARDWARE MANUAL”
52		Changed the figure for “Internal shift clock mode”
54	4. AC Characteristics (10) I^2C timing	Added parameter, “Noise filter” and an annotation *5 for it
		Added t_{SP} to the figure
55	5. A/D Converter (1) Electrical Characteristics for the A/D Converter	Added “Analog impedance”
		Added “Variation between channels”
		Added the annotation
56	5. A/D Converter (2) Accuracy and Setting of the A/D Converter Sampling Time	Deleted the unit “[Min]” from approximation formula of Sampling time
57	5. A/D Converter (3) Definition of A/D Converter Terms	Changed the Description and the figure “Linearity” → “Nonlinearity” “Differential linearity error” “Differential nonlinearity error”
		Changed the Description Linearity error: Deviation of the line between the zero-transition point (0b0000000000←→0b0000000001) and the full-scale transition point (0b1111111110←→0b1111111111) from the actual conversion characteristics. Nonlinearity error: Deviation of the actual conversion characteristics from a straight line that connects the zero transition point (0b0000000000 ←→ 0b0000000001) to the full-scale transition point (0b1111111110 ←→ 0b1111111111).
		Added the Description “Zero transition voltage” “Full scale transition voltage”
59	6. High Current Output Slew Rate	Changed the condition (V_{CC} = AV_{CC} = 2.7V to 5.5V, DV_{CC} = 4.5V to 5.5V, V_{SS} = AV_{SS} = DV_{SS} = 0V, T_A = - 40°C to + 105°C) (V_{CC} = AV_{CC} = DV_{CC} = 2.7V to 5.5V, V_{SS} = AV_{SS} = DV_{SS} = 0V, T_A = - 40°C to + 105°C)
		Changed the Symbol and figure t_{R2}, t_{F2}, V_{OL2} t_{R30}, t_{F30}, V_{OL30}
59	7. Low Voltage Detection Function Characteristics	Added the Value of “ Power supply voltage change rate” Max: +0.004 V/µs
		Added “Hysteresis width” (V_{HYS})
		Added “Stabilization time” ($T_{LVDSTAB}$)
		Added “Detection delay time” (t_d)
		Deleted the Remarks
		Added the annotation *1, *2
59	7. Low Voltage Detection Function Characteristics	Added the figure for “Hysteresis width”
		Added the figure for “Stabilization time”